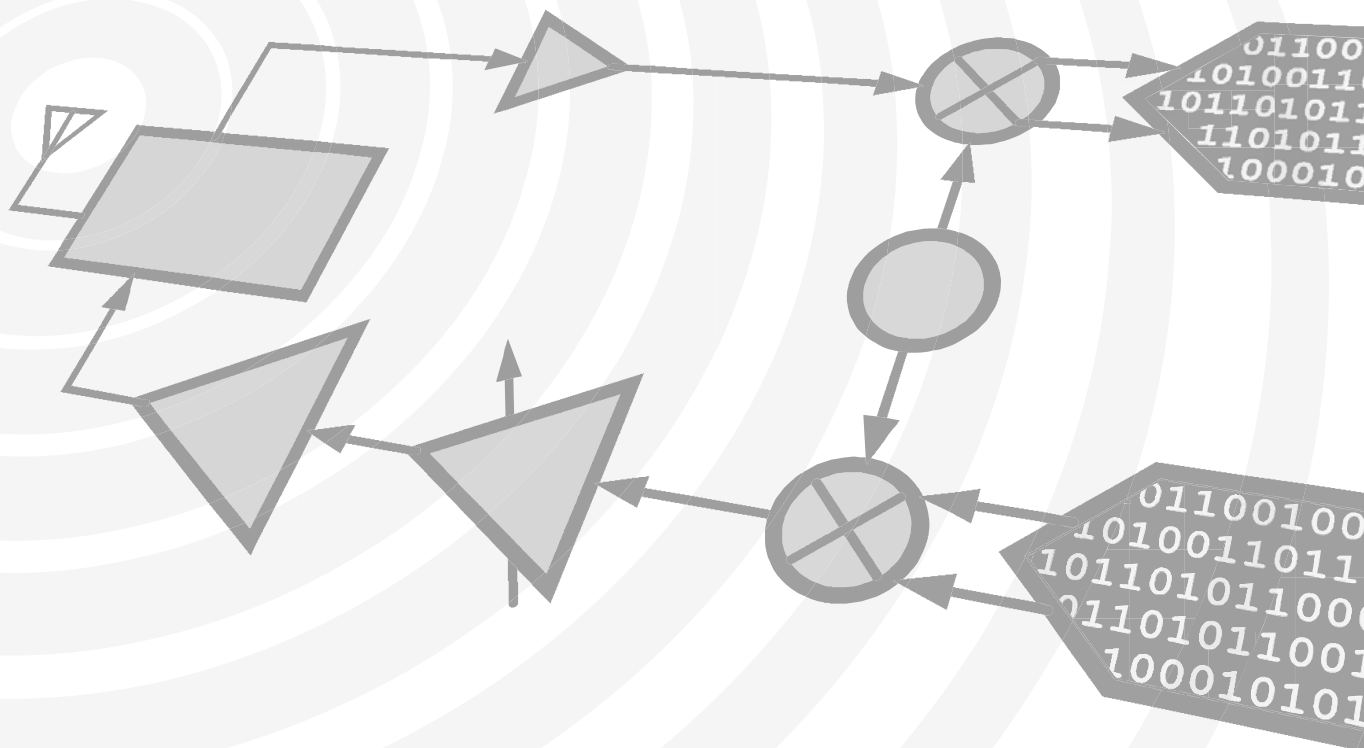




Hittite
MICROWAVE PRODUCTS
FROM ANALOG DEVICES

Analog Devices Welcomes Hittite Microwave Corporation

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MICROWAVE CORPORATION

HMC410AMS8G / 410AMS8GE

v00.0410



GaAs MMIC DOUBLE-BALANCED HIGH IP3 MIXER, 9 - 15 GHz

Typical Applications

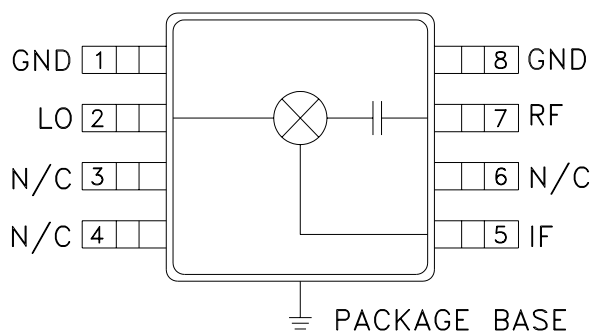
The HMC410AMS8G(E) is ideal for:

- Long Haul Radio Platforms
- Microwave Radio
- VSAT

Features

Conversion Loss: 8 dB
 LO/Rf Isolation: 40 dB
 LO/IF Isolation: 37 dB
 Input IP3: +24 dBm
 No External Components
 MSOP8G SMT Package

Functional Diagram



General Description

The HMC410AMS8G(E) is a passive double-balanced high IP3 mixer that operates between 9 and 15 GHz. The HMC410AMS8G(E) operates with LO drive levels between +13 dBm and +19 dBm, and provides 8 dB conversion loss across the entire specified frequency band. These mixers require no external components or bias.

Electrical Specifications, $T_A = +25^\circ\text{C}$

Parameter	IF = 1.45 GHz LO = +17 dBm			Units
	Min.	Typ.	Max.	
Frequency Range, RF & LO	9 - 15			GHz
Frequency Range, IF	DC - 2.5			GHz
Conversion Loss		8	11	dB
Noise Figure (SSB)		8	11	dB
LO to RF Isolation	30	40 - 45		dB
LO to IF Isolation	30	37		dB
RF to IF Isolation	8	17		dB
IP3 (Input)	20	24		dBm
1 dB Compression (Input)	11	14		dBm

* Unless otherwise noted, all measurements performed as downconverter, IF = 1.45 GHz.

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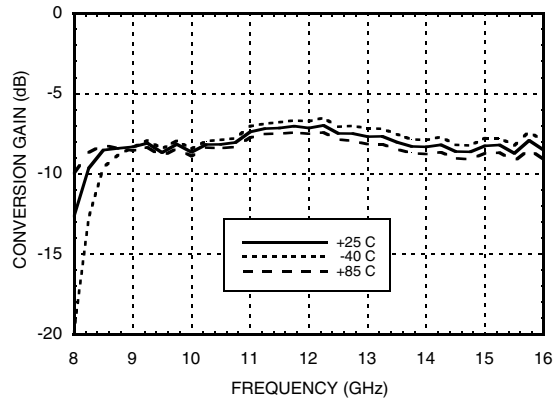
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

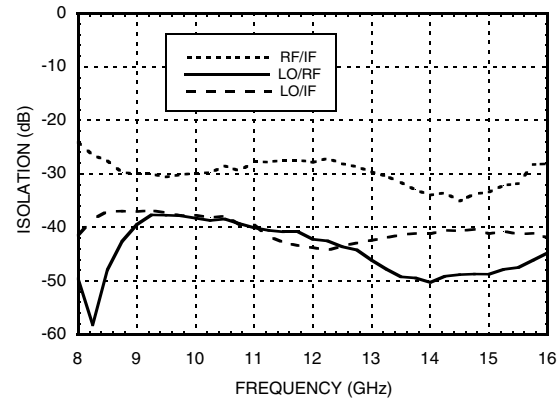
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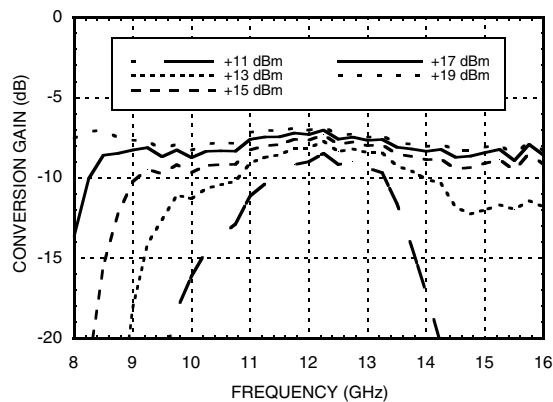
**Conversion Gain vs.
Temperature @ LO = +17 dBm**



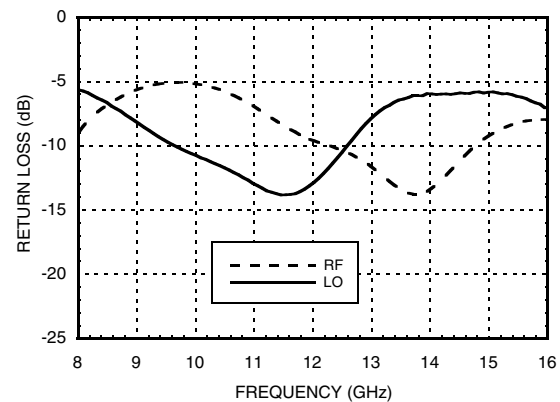
Isolation @ LO = +17 dBm



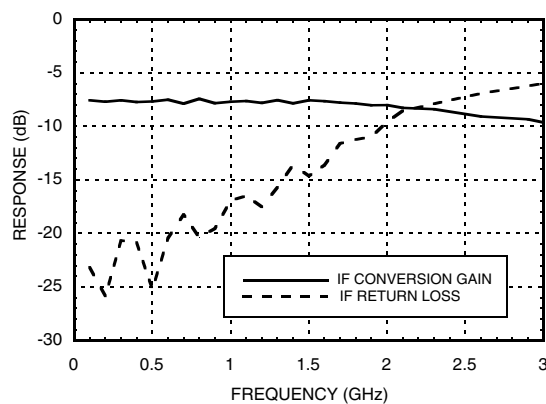
Conversion Gain vs. LO Drive



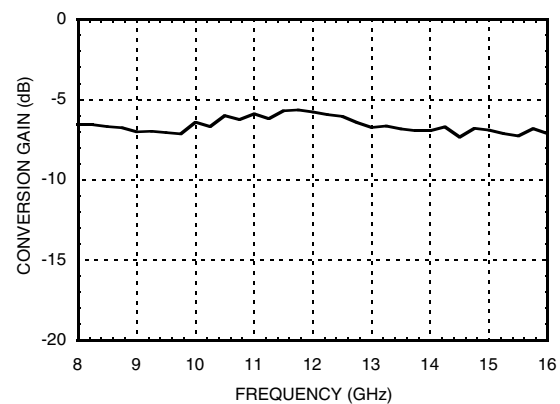
Return Loss @ LO = +17 dBm



IF Bandwidth @ LO = +17 dBm

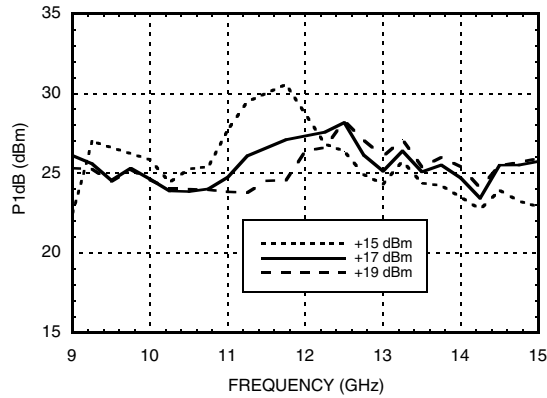


**Upconverter Performance
Conversion Gain @ LO = +17 dBm**

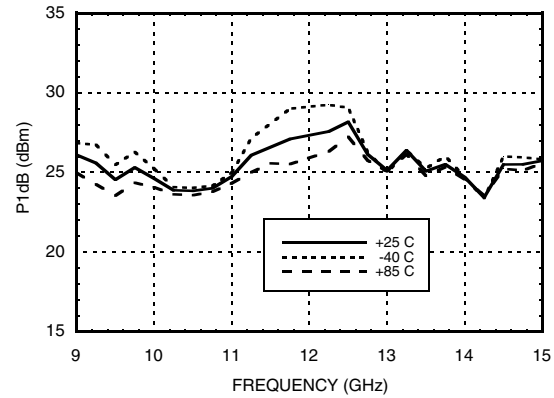


GaAs MMIC DOUBLE-BALANCED HIGH IP3 MIXER, 9 - 15 GHz

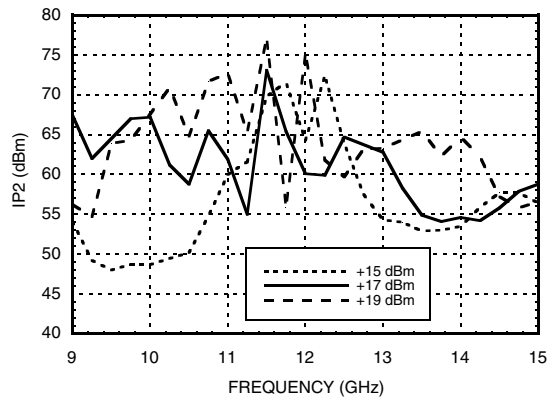
Input IP3 vs. LO Drive*



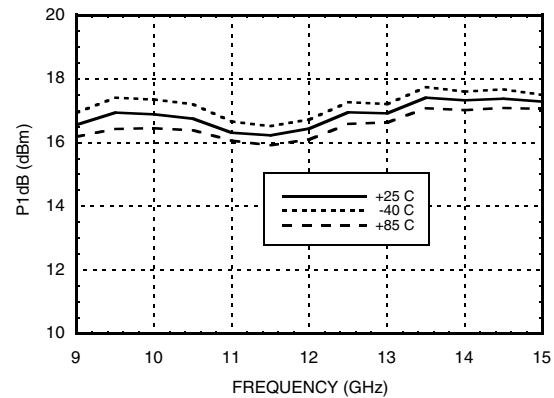
**Input IP3 vs.
Temperature @ LO = +17 dBm***



Input IP2 vs. LO Drive *



**Input P1dB vs.
Temperature @ LO = +17 dBm**



MxN Spurious @ IF Port

	nLO				
mRF	0	1	2	3	4
0	XX	4	28	23	N/A
1	15	0	40	62	46
2	85	70	67	78	83
3	>90	>90	>90	79	>90
4	N/A	>90	>90	>90	>90

RF = 14.45 GHz @ -10 dBm
LO = 13 GHz @ +17 dBm
All values in dBc relative to the IF power level.
Measured as downconverter.

Harmonics of LO

	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
9	34	28	46	60
10.5	37	37	50	69
12	44	45	46	60
13.5	47	46	62	N/A
15	40	56	58	N/A
16.5	34	47	51	N/A

LO = +17 dBm
All values in dBc below input LO level @ RF port.

* Two-tone input power = 0 dBm each tone, 1 MHz spacing.

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HMC410AMS8G / 410AMS8GE

**GaAs MMIC DOUBLE-BALANCED
HIGH IP3 MIXER, 9 - 15 GHz**

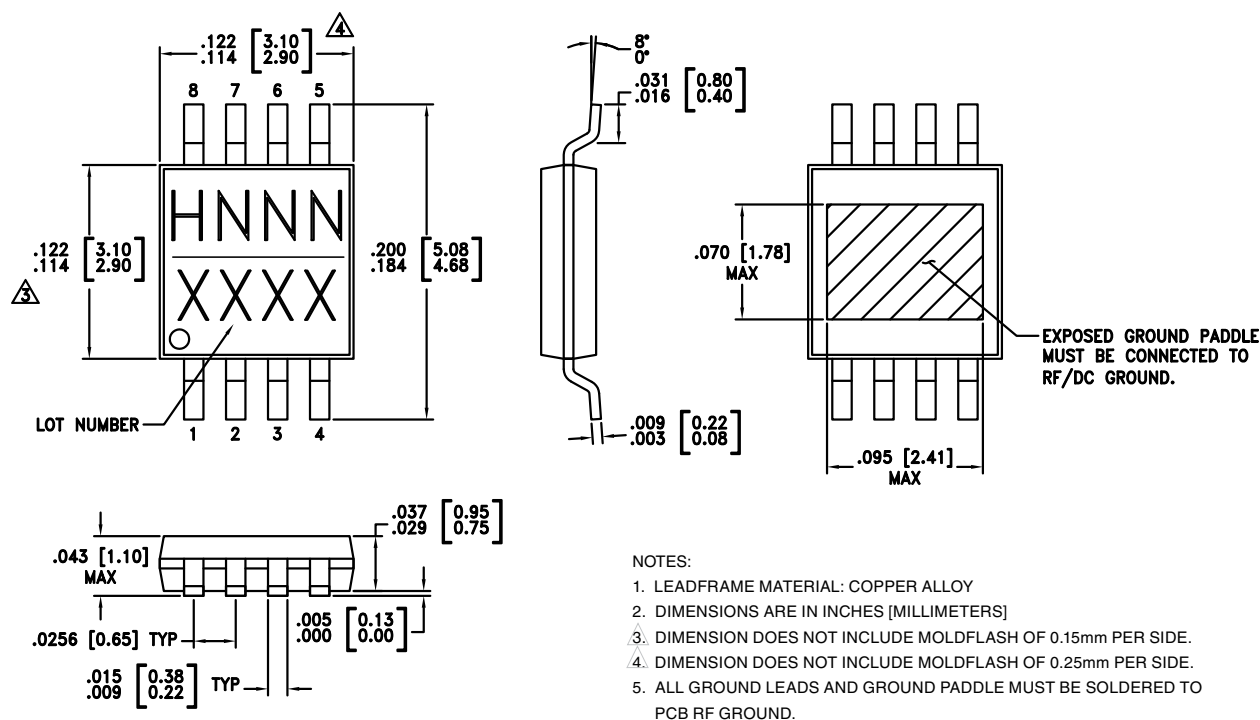
Absolute Maximum Ratings

RF / IF Input	+20 dBm
LO Drive	+27 dBm
IF DC Current	±4 mA
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC410AMS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H410A XXXX
HMC410AMS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H410A</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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10

MIXERS - SINGLE & DOUBLE BALANCED - SMT



MICROWAVE CORPORATION

v00.0410



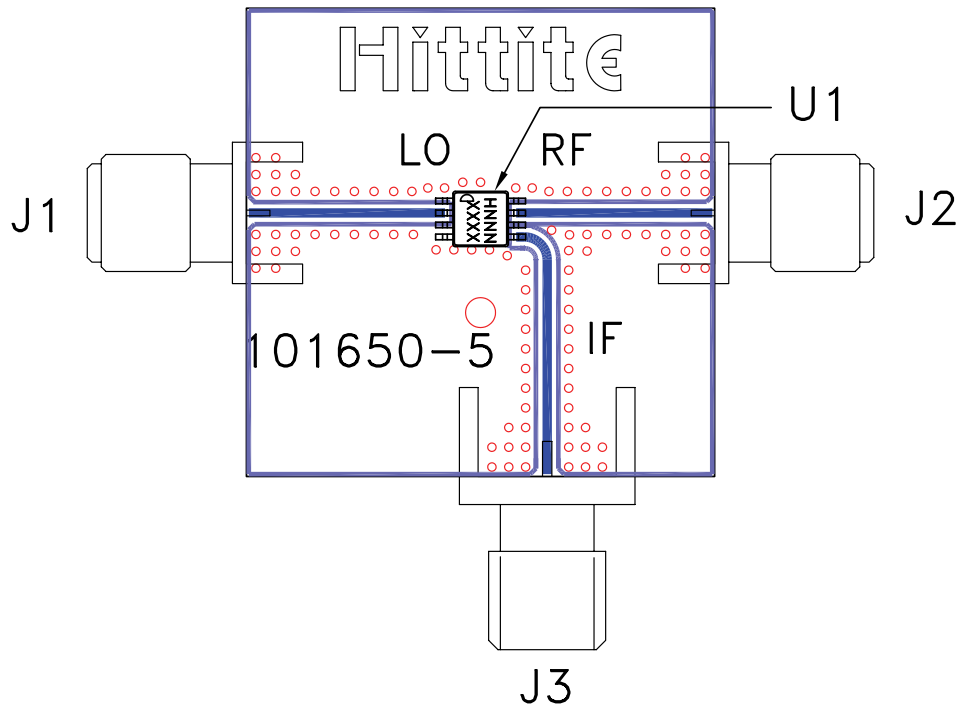
HMC410AMS8G / 410AMS8GE

GaAs MMIC DOUBLE-BALANCED HIGH IP3 MIXER, 9 - 15 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 8	GND	Pins and exposed ground slug must be connected to RF ground.	
2	LO	This pin is AC coupled and matched to 50 Ohms.	
3, 4, 6	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
5	IF	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source/sink more than 4mA of current or die non-function and possible die failure will result.	
7	RF	This pin is DC coupled and matched to 50 Ohms.	

Evaluation PCB



List of Materials for Evaluation PCB 103350 ^[1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector, SRI
J3	PCB Mount SMA Connector, Johnson
U1	HMC410AMS8G(E) Mixer
PCB [2]	101650 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.